DESCRIPTION

The DRS1AF~DRS1MF are available in SMAF Package

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Fast reverse recovery time
- Available in SMAF Package

ORDERING INFORMATION

Package Type	Part Number			
SMAF	DRS1AF			
	DRS1BF			
	DRS1DF			
	DRS1GF DRS1JF			
	DRS1MF			
	Note	SPQ: 3,000pcs/Reel		
AiT provides all RoHS Compliant Products				

PIN DESCRIPTION

CATHODE

MECHANICAL DATA

Case: SMAF

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 27mg 0.00086oz

DRS1AF~DRS1MF

FAST RECOVERY RECTIFIER DIODE REVERSE VOLTAGE 50V TO 1000V FORWARD CURRENT 1A

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter		Symbol	DRS1AF	DRS1BF	DRS1DF	DRS1GF	DRS1JF	DRS1KF	DRS1MF	Unit
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Volta	ge	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blockin	ng Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at T _A =65°C		I _{F(AV)}	1.0						Α	
Peak Forward Surge 8.3ms Single Half Sir Superimposed on Ra (JEDEC Method)	ne Wave	lгsм	25					А		
Maximum Instantaneous Forward Voltage at 1A		V _F	1.3						V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	T _A =25°C T _A =125°C	I _R	5.0 100					μΑ		
Maximum Reverse Recovery TimeNOTE1		t _{rr}	150 250 500					ns		
Typical Junction Capacitance ^{NOTE2}	C ₁			15						рF
Operating and Storag Temperature Range	T _J , T _{STG}	-55 ~150						°C		

NOTE1: Measured with $I_F \! = \! 0.5 A, \, I_R \! = \! 1A, \, I_{rr} \! = \! 0.25 A$

NOTE2: Measured at 1MHz and applied reverse voltage of 4V D.C

TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

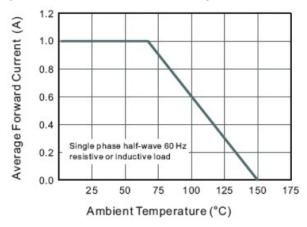


Figure. 3 Typical Instantaneous Forward

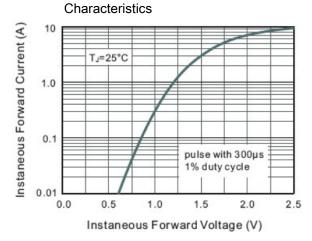


Figure. 5 Maximum Non-Repetitive Peak Forward

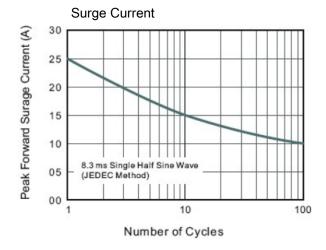


Figure. 2 Typical Reverse Characteristics

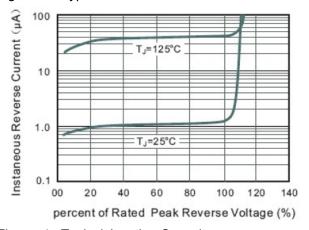
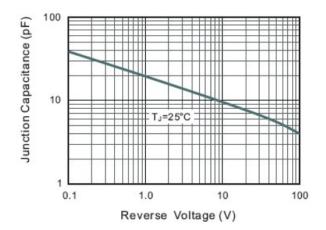


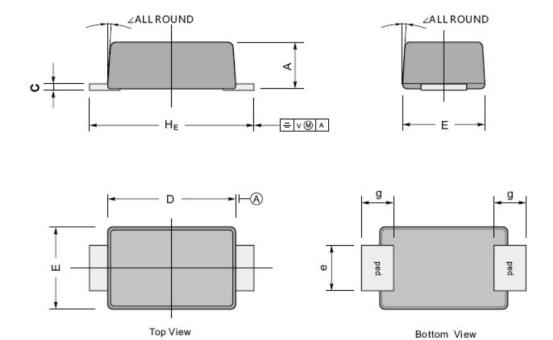
Figure. 4 Typical Junction Capacitance



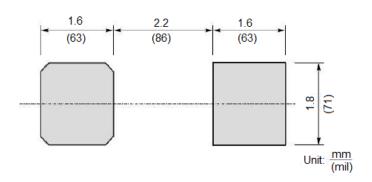
PACKAGE INFORMATION

Dimension in SMAF (Unit: mm)

Plastic surface mounted package; 2 leads



The recommended mounting pad size



UN	NIT	A	C	D	ш	е	g	HE	∠
mm	Max	1.1	0.20	3.7	2.7	1.6	1.2	4.9	
	Min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	7°
mil	Max	43	7.9	146	106	63	47	193	,
	Min	35	4.7	130	94	51	31	173	

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